1. QUARTZ CRYSTAL UNIT SPECIFICATION

Parameter	Sign	Specification
1.1 Nominal Frequency :	F0	27.120MHz
1.2 Holder type :	-	FTX321S (SMD3225 SEAM TYPE)
1.3 Mode of oscillation :	-	Fundamental
1.4 Frequency tolerance:	FL	±30ppm at 25℃±3℃
1.5 Equivalent resistance :	RR	40ohms max.
1.6 Operating temperature range :	T _{OPR}	-40℃ To +85℃
1.7 Storage temperature range :	T _{STG}	-55℃ To +125℃
1.8 Frequency Stability :	TC	±30ppm at -40°C To +85°C
1.9 Loading capacitance :	CL	20pF
1.10 Drive level :	DL	10 uW Typical, 100uW max.
1.11 Shunt Capacitance :	C0	2.0pF max.
1.12 Insulation resistance :	IR	More than $500M\Omega$ at DC $100V$
1.13 Circuit:	-	Measured in HP/E5100A,S&A 250B
1.14 Aging :	Fa	±3ppm max. (+25°C 1 st Year)
1.15 Dimensions and marking :		Refer to page.4
1.16 Emboss carrier tape & reel :		Refer to page.5 and page.6

Standard atmospheric conditions

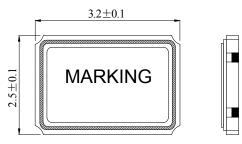
Unless otherwise specified, the standard range of atmospheric conditions for making measurement and tests are as follow:

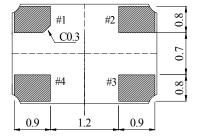
Ambient temperature : $25\pm3^{\circ}$ C Relative humidity : $40\%\sim70\%$

1.17 Note:

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2. FTX321S MARKING & DIMENSIONS

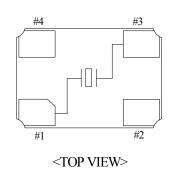


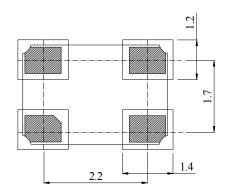




Marking #2, #4 is connected with metal cap of top.

(UNIT: mm)





Recommended Solder Pad Layout:

*Marking should be printed as following:

Logo, Nominal Frequency

*Manufacturing Logo: FT

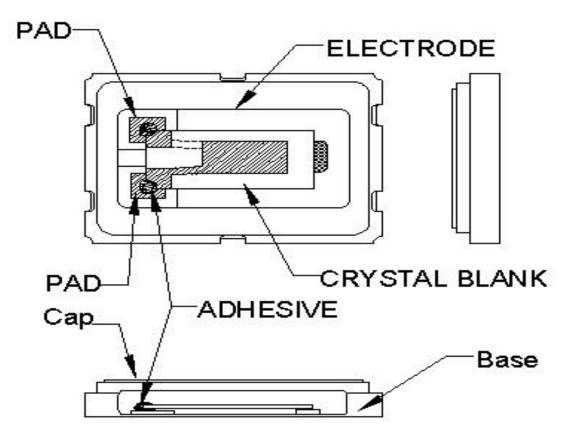
*Nominal frequency = 3 number after decimal point MAX.

(ex. $12.000 \text{ MHz} \rightarrow 12.000$)

Marking: Laser marking

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3. INSIDE STRUCTURE



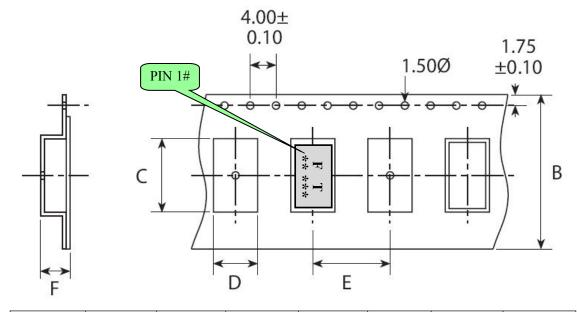
Reference drawing

Base:
Alumina Ceramic (Al ₂ O ₃)
Metallized Pad: W
Ni Plating
Au Plating
Сар:
Fe-Ni
(3) Crystal Enclosure Seal:
Seal Seam
(4) Crystal Blank
Rectangular At-Cut Quartz Crystal Blank
(5) Adhesive
Silver Conductive Polyimide Resin
(6) Electrode
Ag
(7) PAD
Alumina Ceramic (W. Ni. Au)

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4. FTX321S EMBOSS CARRIER TAPE & REEL

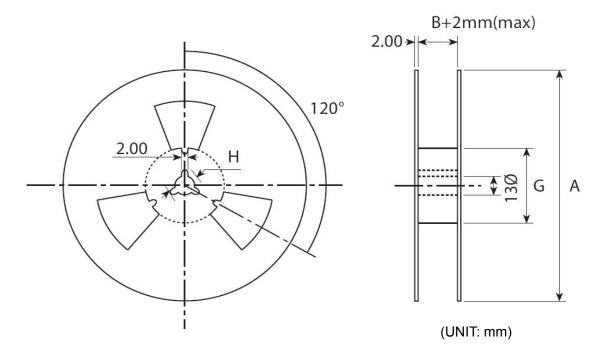
a.) Dimensions of Carrier Tape



	A	В	С	D	Е	F	G	
SMD3225	178±2.0	8.0±0.3	3.5±0.1	2.8±0.1	4.0±0.1	1.4±0.1	60.5±1.0	

(UNIT: mm)

b.) Dimensions of Reel



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c.) Storage condition

Temperature: +40deg.C Max. Relative Humidity: 80% Max.

d.) Standard packing quantity

3,000PCS / REEL

e.) Material of the tape

Tape	Material
Carrier tape	A – PET
Top tape	Polyester

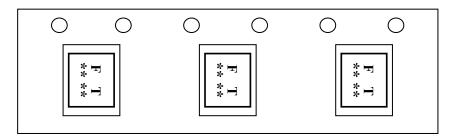
- f.) Label contents
 - .The type of product
 - .Our specification No.
 - .Your Part No.
 - .Lot No.
 - .Nominal Frequency
 - .Quantity
 - .Our Company Name

Sticks	label	for	every	reel.
Olicks	Iabei	101	CVCIV	1001

PART NUMBER		
PO NO		
PR. NO:		
HOLDER TYPE		
FREQUENCY		
REMAKS		
QUANTITY		
CHIP SUN TECHNOLOGY CO., LTD		

g.) Taping method

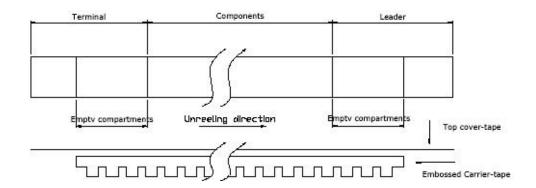
Taping shall be placed in tapes in such manner as to assure that marking of the components is visible as per Fig.1



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h.) Taping dimension

Cover-tape	The length of cover-tape in the leader is more than 400 mm including empty embossed area.	
Leader Carrier-tape		After all products were packaged, must remain more than twenty pieces or 400 mm empty area, which should be sealed by cover-tape.
Torminal	Cover-tape	The tip of cover-tape shall be fixed temporary by paper tape and roll around the core of reel one round.
Terminal	Carrier-tape	The empty embossed area which are sealed by top cover-tape must remain more the 40 mm.



i.) Joint of tape

The carrier-tape and top cover-tape should not be jointed.

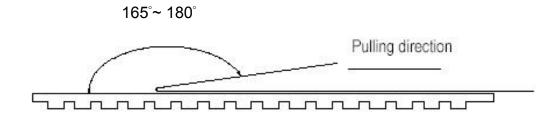
j.) Release strength of cover tape

It has to between 0.1N to 0.7N under following condition.

Pulling direction 165° to 180°

Speed 300mm/min.

Otherwise unless specified.

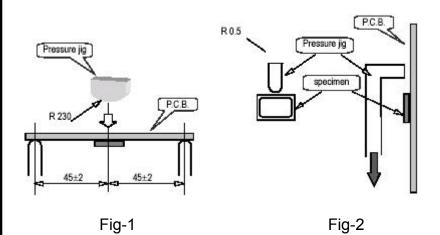


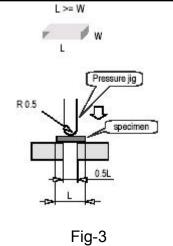
Other standards shall be based on JIS C 0806-1990.

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5. Mechanical Endurance: Provided that measurement shall be carried out afterletting it alone in the room temperature for 1 hour.

	Item	Conditions	Specifications
5.1	Drop	Fall freely from 100 cm of height 3 times on a firm wood	MIL-STD-202F-203B
5.2	Mechanical Shock	Device are shocked to half sine wave (1000 G) three mutually perpendicular axes each 3 times.	MIL-STD-202F
5.3	Vibration	 (1)Vibration Frequency: 10~55Hz (2)Cycle: 1 to 2 Min. (3)Full Cycle: 1.5mm P-P. (4)Direction: X.Y.Z (5)Time: 2 Hours / Each Direction 	MIL-STD-883E
5.4	Substrate Bending	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –1 Speed: 0.5 mm/sec Hours: 5 ± 1 sec Amount of substrate: 3 mm Max.	Without mechanical
5.5	Adhesion	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –2 Weight: 10N Hours: 10 ± 1 sec	damage such as breaks. Without electrode peeling. Electrical characteristics shall be satisfied.
5.6	Body strength	Mount the specimen on substrate. Apply the following pressure Direction: see Fig –3 Weight: 10N Hours: 10 ± 1 sec	
5.7	Seal	Fine Leak: 4.5kgf/cm ² 2hours 1×10 ⁻⁹ Pa.m ³ /sec Gross Leak: 4.5kgf/cm ² 2hours 1.5×10 ⁻⁵ Pa.m ³ /sec	MIL-STD-883E





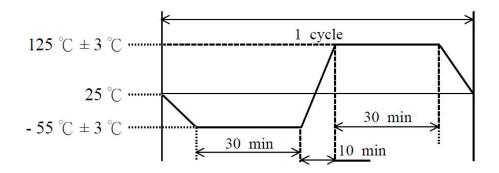
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- L	lder ility	Pre-heat temperature: +150±10°C Pre-heat time: 60~120s When the temperature of the specimen is reached at +215±3°C, it shall be left for 30±1sec. Peak temperature 240±5°C Material: Pb-free (Sn-3.0Ag-0.5Cu) Flux: Rosin resin methyl alcohol solvent (1:4) The electrodes should be covered by a new solder at least 90% of immersed area.	MIL-STD-883E 2003
Resis to Solde Heat		Run in Reflow Reflow soldering shall be allowed Only two(2) time. Available for Lead Free Soldering PEAK 260±5°C 10s PEAK 260±5°C 10s TIME (Seconds) Total: (1) Preheat 160~180 deg.C 120sec. (2) Primary heat 220 deg.C 60sec. (3) Peak 260 deg.C 10sec. Max.	MIL-STD-202F

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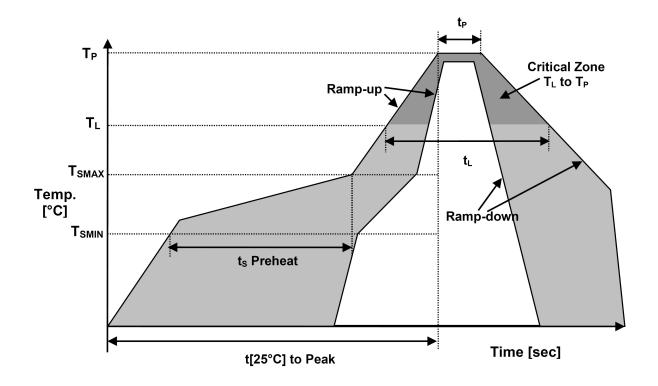
6. Environmental Endurance: Provided that measurement shall be carried out afterletting it alone in the room temperature for 1 hour.

	Item	Conditions	Specifications
6.1	Humidity	+60℃±2℃,RH 80~85%, Duration of 500 hours. The units are then allowed to stand for approx 2 hours in room temperature before checking	MIL-STD-202F
6.2	Storage in Low Temperature	Temperature: -40 ± 2 °C , Duration of 500 hours. The units are then allowed to stand at room temperature for approx 2 hours before checking.	MIL-STD-883E
6.3	Storage in High Temperature	Temperature:+85 $^{\circ}$ C±2 $^{\circ}$, Duration of 500 hours. The units are then allowed to stand at room temperature for approx 2 hours before checking.	MIL-STD-883E
6.4	Thermal Shock	Temperature 1: -55°C±5°C Temperature 2: 125°C±5°C Temperature change between T1 and T2 at soonest Run 100 cycles, maintain T1 and T2 30minutes each in one cycle (Refer to Fig-4)	MIL-STD-883E



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7. Recommended Solder Reflow Profile



Temperature Min Preheat	T _{SMIN}	150℃
Temperature Max Preheat	T _{SMAX}	175℃
Time (T _{SMIN} to T _{SMAX})	ts	60-180 sec.
Temperature	TL	217℃
Peak Temperature	T _P	260℃
Ramp-up rate	Rup	3℃/sec max.
Ramp-down rate	R _{DOWN}	6°C/sec max.
Time within 5°C of Peak Temperature	t _P	10 sec max.
Time t[25°C] to Peak Temperature	t[25°C] to Peak	480 sec max.
Time	t _L	60-150 sec.

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